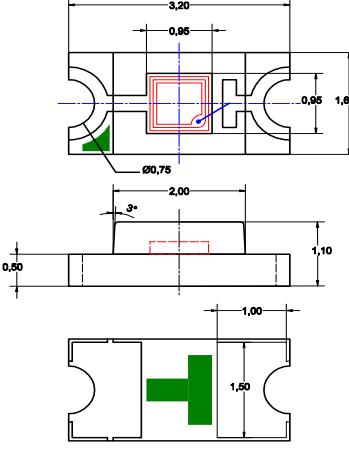
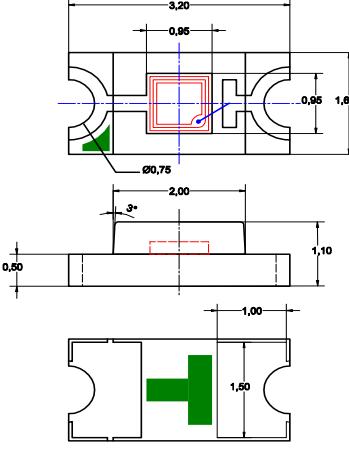


Wavelength	Type	Technology	Case
Infrared	SMD	GaAs	SMD 1206

	Description
	Selective photodiode with narrow bandwidth and high spectral sensitivity in the infrared range (810...950 nm). Compact design in standard SMD package allows for easy circuit board mounting and assembling of arrays.
	Applications
	Alarm systems, light barriers, special sensors

Miscellaneous Parameters

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Value	Unit
Active area		A	0.62	mm^2
Temperature coefficient of I_D		TCl_D	5	%/K
Operating temperature range		T_{amb}	-20 to +85	°C
Storage temperature range		T_{stg}	-40 to +125	°C

Optical and Electrical Characteristics

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Min	Typ	Max	Unit
Breakdown voltage ¹⁾	$I_R = 10 \mu\text{A}$	V_R	5			V
Dark current	$V_R = 1 \text{ V}$	I_D		1.0	2.5	nA
Peak sensitivity wavelength	$V_R = 0 \text{ V}$	λ_p		890		nm
Responsivity at λ_p	$V_R = 0 \text{ V}$	S_λ	0.3	0.55		A/W
Sensitivity range at 10% ¹⁾	$V_R = 0 \text{ V}$	$\lambda_{min}, \lambda_{max}$	800		960	nm
Spectral bandwidth at 50%	$V_R = 0 \text{ V}$	$\Delta\lambda_{0.5}$		115		nm
Shunt resistance	$V_R = 10 \text{ mV}$	R_{SH}		205		$\text{G}\Omega$
Noise equivalent power	$\lambda = 880 \text{ nm}$	NEP		3.2×10^{-14}		$\text{W}/\sqrt{\text{Hz}}$
Specific detectivity	$\lambda = 880 \text{ nm}$	D^*		2.4×10^{12}		$\text{cm} \cdot \sqrt{\text{Hz}} \cdot \text{W}^{-1}$
Junction capacitance	$V_R = 0 \text{ V}$	C_J		500		pF
Switching time ($R_L = 50 \Omega$)	$V_R = 1 \text{ V}$	t_r, t_f		175		ns

¹⁾for information only

Labeling

Type	Lot N°	Typ. S_λ [A/W]	Quantity
EPD-880-1-0.9-1			

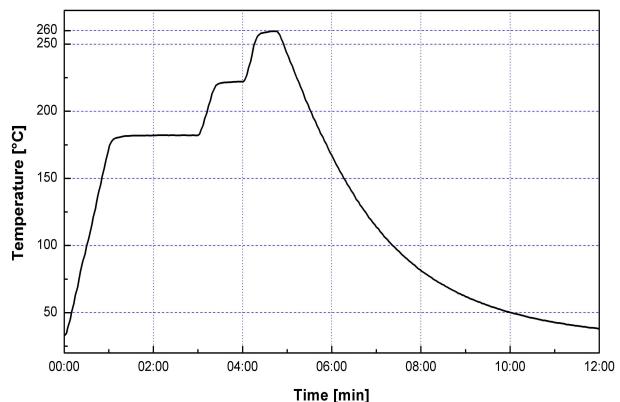
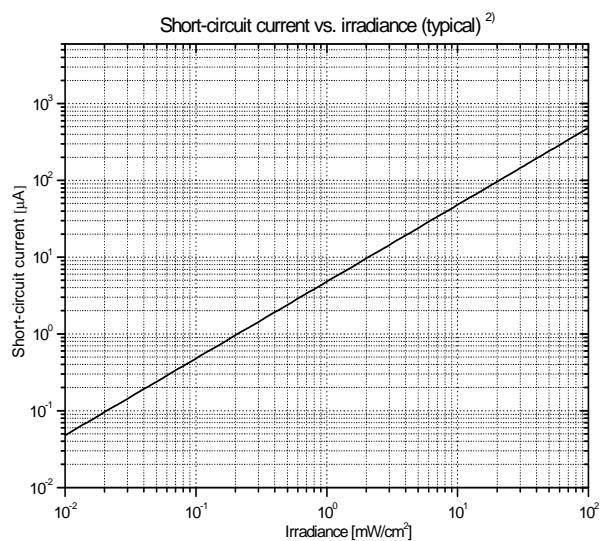
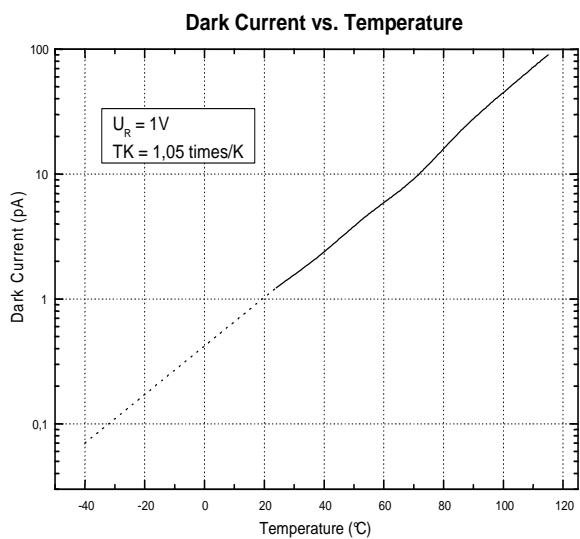
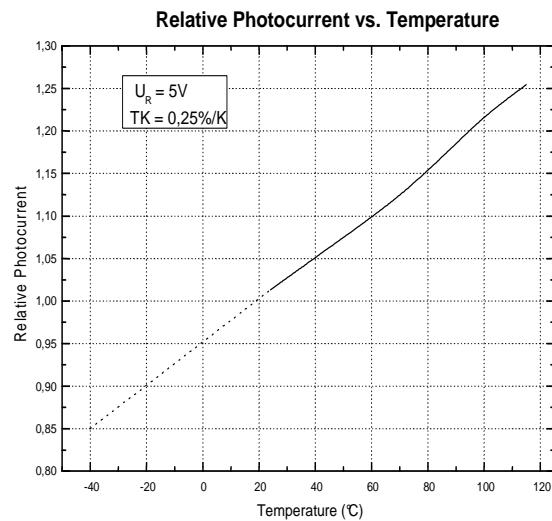
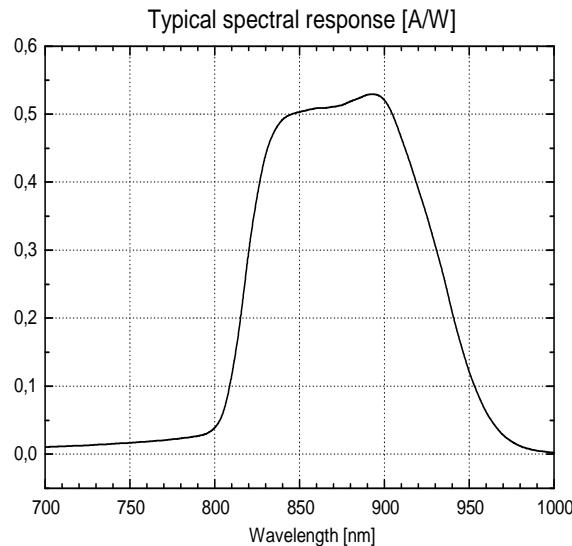
*Note: All measurements carried out with *EPIGAP* equipment

We reserve the right to make changes to improve technical design and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer.

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